# TIP41A/41B/41C TIP42A/42C

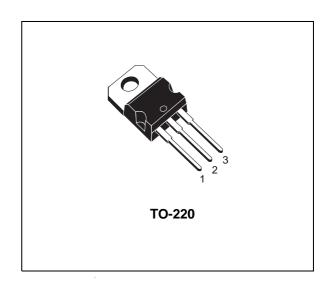
# COMPLEMENTARY SILICON POWER TRANSISTORS

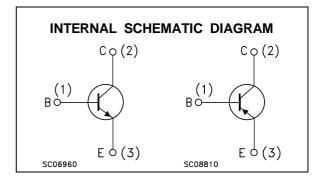
#### ■ COMPLEMENTARY PNP - NPN DEVICES

#### **DESCRIPTION**

The TIP41A, TIP41B and TIP41C are silicon Epitaxial-Base NPN power transistors mounted in Jedec TO-220 plastic package. They are intented for use in medium power linear and switching applications.

The TIP41A and TIP41C complementary PNP types are TIP42A and TIP42C respectively.





#### **ABSOLUTE MAXIMUM RATINGS**

Symbol	Parameter			Unit		
		NPN	TIP41A	TIP41B	TIP41C	1
		PNP	TIP42A		TIP42C	1
V <sub>CBO</sub>	Collector-Base Voltage (I <sub>E</sub> = 0)		60	80	100	V
V <sub>CEO</sub>	Collector-Emitter Voltage (I <sub>B</sub> = 0)		60	80	100	V
V <sub>EBO</sub>	Emitter-Base Voltage (I <sub>C</sub> = 0)			5		V
Ic	Collector Current			Α		
I <sub>CM</sub>	Collector Peak Current			Α		
Ι <sub>Β</sub>	Base Current		3			Α
P <sub>tot</sub>	Total Dissipation at T <sub>case</sub> ≤ 25 °C			65		W
	T <sub>amb</sub> ≤ 25 °C			2		W
T <sub>stg</sub>	Storage Temperature		-65 to 150			°C
Ti	Max. Operating Junction Temperature		150			°C

For PNP types voltage and current values are negative.

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### TIP41A/TIP41B/TIP41C/TIP42A/TIP42C

#### THERMAL DATA

R <sub>thj-case</sub>	Thermal Resistance Junction-case	Max	1.92	°C/W
R <sub>thj-amb</sub>	Thermal Resistance Junction-ambient	Max	62.5	°C/W

## **ELECTRICAL CHARACTERISTICS** (T<sub>case</sub> = 25 °C unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
I <sub>CEO</sub>	Collector Cut-off Current (I <sub>B</sub> = 0)	for <b>TIP41A/42A</b> V <sub>CE</sub> = for <b>TIP41B/41C/42C</b> V <sub>CE</sub> =	= 30 V = 60 V		0.7 0.7	mA mA
I <sub>CES</sub>	Collector Cut-off Current (V <sub>BE</sub> = 0)	0=	= 60 V = 80 V = 100 V		0.4 0.4 0.4	mA mA mA
I <sub>EBO</sub>	Emitter Cut-off Current (I <sub>C</sub> = 0)	$V_{EB} = 5 V$			1	mA
V <sub>CEO(sus)</sub> *	Collector-Emitter Sustaining Voltage (I <sub>B</sub> = 0)	I <sub>C</sub> = 30 mA for TIP41A/42A for TIP41B for TIP41C/42C	60 80 100			V V V
V <sub>CE(sat)</sub> *	Collector-Emitter Saturation Voltage	$I_C = 6 A$ $I_B = 0$	.6 A		1.5	V
V <sub>BE(on)</sub> *	Base-Emitter Voltage	Ic = 6 A Vce =	4 V		2	V
h <sub>FE</sub> *	DC Current Gain	$I_C = 0.3 \text{ A}$ $V_{CE} = I_C = 3 \text{ A}$ $V_{CE} = I_C = 3 \text{ A}$			75	
h <sub>fe</sub>	Small Signal Current Gain	$I_C = 0.5 \text{ A}$ $V_{CE} = 10 \text{ V}$ $f = I_C = 0.5 \text{ A}$ $V_{CE} = 10 \text{ V}$ $f = 10 \text{ V}$				

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<sup>\*</sup> Pulsed: Pulse duration = 300  $\mu$ s, duty cycle  $\leq$  2 % For PNP types voltage and current values are negative.

## **TO-220 MECHANICAL DATA**

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
Α	4.40		4.60	0.173		0.181
С	1.23		1.32	0.048		0.051
D	2.40		2.72	0.094		0.107
D1		1.27			0.050	
Е	0.49		0.70	0.019		0.027
F	0.61		0.88	0.024		0.034
F1	1.14		1.70	0.044		0.067
F2	1.14		1.70	0.044		0.067
G	4.95		5.15	0.194		0.203
G1	2.4		2.7	0.094		0.106
H2	10.0		10.40	0.393		0.409
L2		16.4			0.645	
L4	13.0		14.0	0.511		0.551
L5	2.65		2.95	0.104		0.116
L6	15.25		15.75	0.600		0.620
L7	6.2		6.6	0.244		0.260
L9	3.5		3.93	0.137		0.154
DIA.	3.75		3.85	0.147		0.151

